

Vishay Semiconductors

COMPLIANT HALOGEN

FREE

# Fast Soft Recovery Rectifier Diode, 20 A



#### **LINKS TO ADDITIONAL RESOURCES**



PRIMARY CHARACTERISTICS							
I <sub>F(AV)</sub>	20 A						
V <sub>R</sub>	800 V, 1000 V, 1200 V						
V <sub>F</sub> at I <sub>F</sub>	1.31 V						
I <sub>FSM</sub>	320 A						
t <sub>rr</sub>	95 ns						
T <sub>J</sub> max.	150 °C						
Snap factor	0.6						
Package	TO-220AC 2L						
Circuit configuration	Single						

### **FEATURES**

- · Glass passivated pellet chip junction
- 150 °C max operating junction temperature
- Low forward voltage drop and short reverse recovery time
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **APPLICATIONS**

These devices are intended for use in output rectification and freewheeling in inverters, choppers and converters as well as in input rectification where severe restrictions on conducted EMI should be met.

## **DESCRIPTION**

The VS-20ETF... fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

### **MECHANICAL DATA**

Case: TO-220AC 2L

Molding compound meets UL 94 V-0 flammability rating

Terminals: matte tin plated leads, solderable per

J-STD-002

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	CHARACTERISTICS	VALUES	UNITS					
V <sub>RRM</sub>		800 to 1200						
I <sub>F(AV)</sub>	Sinusoidal waveform	20	^					
I <sub>FSM</sub>		320	Α Α					
t <sub>rr</sub>	1 A, 100 A/µs	95	ns					
V <sub>F</sub>	20 A, T <sub>J</sub> = 25 °C	1.31	V					
T <sub>J</sub>	Range	-40 to +150	°C					

VOLTAGE RATINGS									
PART NUMBER	V <sub>RRM</sub> , MAXIMUM PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> AT 150 °C mA						
VS-20ETF08-M3	800	900							
VS-20ETF10-M3	1000	1100	6						
VS-20ETF12-M3	1200	1300							

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum average forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 113 °C, 180° conduction half sine wave	20					
Maximum peak one cycle	I <sub>FSM</sub>	10 ms sine pulse, rated V <sub>RRM</sub> applied 270		Α				
non-repetitive surge current		10 ms sine pulse, no voltage reapplied	320					
Maximum I <sup>2</sup> t for fusing	I <sup>2</sup> t	10 ms sine pulse, rated V <sub>RRM</sub> applied	365	A <sup>2</sup> s				
Maximum i-t for fusing	I-I	10 ms sine pulse, no voltage reapplied 515		A-5				
Maximum I <sup>2</sup> √t for fusing	I <sup>2</sup> √t	t = 0.1 ms to 10 ms, no voltage reapplied	5150	A²√s				

Revision: 29-Nov-2021 1 Document Number: 96214



# Vishay Semiconductors

ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST COI	VALUES	UNITS				
Maximum forward voltage drop	$V_{FM}$	20 A, T <sub>J</sub> = 25 °C	1.31	V				
Forward slope resistance	r <sub>t</sub>	T <sub>.1</sub> = 150 °C	11.88	mΩ				
Threshold voltage	V <sub>F(TO)</sub>	1j = 130 C	0.93	V				
Maximum reverse leakage current	I <sub>RM</sub>	T <sub>J</sub> = 25 °C	$V_{R}$ = Rated $V_{RRM}$	0.1	mΛ			
iviaximum reverse leakage current		T <sub>J</sub> = 150 °C	VR = nated VRRM	6	mA			

RECOVERY CHARACTERISTICS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES UNITS		· •				
Reverse recovery time	t <sub>rr</sub>	In at 20 And	400	ns	I <sub>FM</sub> t				
Reverse recovery current	I <sub>rr</sub>	I <sub>F</sub> at 20 A <sub>pk</sub> 25 A/μs	6.1	Α	$t_a \mid t_b$				
Reverse recovery charge	Q <sub>rr</sub>	25 °C	1.7	μC	dir/Q,,				
Snap factor	S	Typical	0.6		dt $Q_{rr}$				

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-40 to +150	°C				
Maximum thermal resistance, junction to case	$R_{thJC}$	DC operation	0.9					
Maximum thermal resistance, junction to ambient	R <sub>thJA</sub>		62	°C/W				
Typical thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, smooth and greased	0.5					
Approximate weight			2	g				
Approximate weight			0.07	oz.				
Mounting torque minimum			6 (5)	kgf ⋅ cm				
Mounting torque maximum			12 (10)	(lbf ⋅ in)				
Marking device		Case style TO-220AC 2L	20E	TF08 TF10 TF12				

Revision: 29-Nov-2021 **2** Document Number: 96214 For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u>



# Vishay Semiconductors

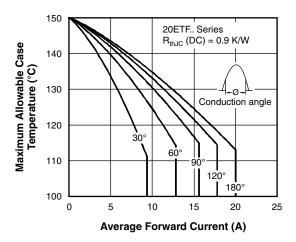


Fig. 1 - Current Rating Characteristics

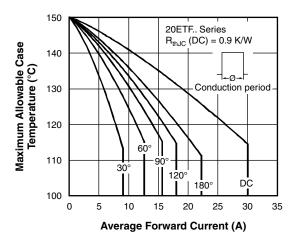


Fig. 2 - Current Rating Characteristics

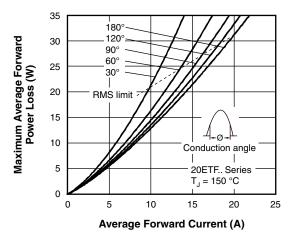


Fig. 3 - Forward Power Loss Characteristics

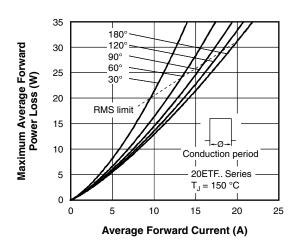


Fig. 4 - Forward Power Loss Characteristics

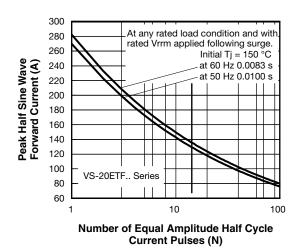


Fig. 5 - Maximum Non-Repetitive Surge Current

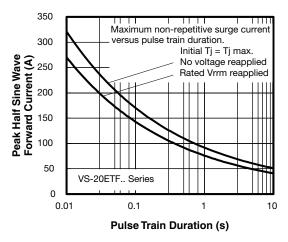


Fig. 6 - Maximum Non-Repetitive Surge Current

# Vishay Semiconductors

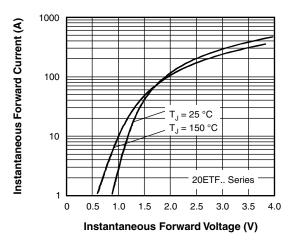


Fig. 7 - Forward Voltage Drop Characteristics

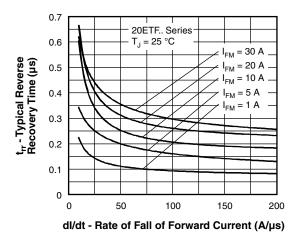


Fig. 8 - Recovery Time Characteristics, T<sub>J</sub> = 25 °C

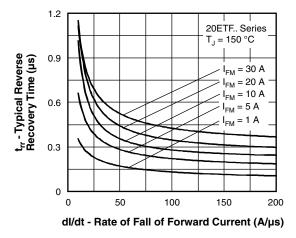


Fig. 9 - Recovery Time Characteristics, T<sub>J</sub> = 150 °C

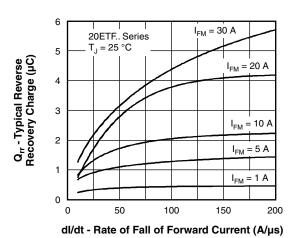


Fig. 10 - Recovery Charge Characteristics,  $T_J = 25$  °C

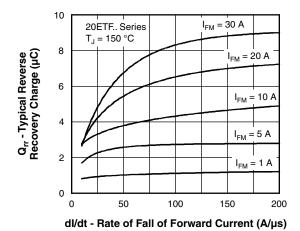


Fig. 11 - Recovery Charge Characteristics,  $T_J$  = 150 °C

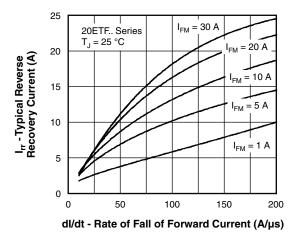


Fig. 12 - Recovery Current Characteristics, T<sub>J</sub> = 25 °C

Revision: 29-Nov-2021 4 Document Number: 96214

Vishay Semiconductors

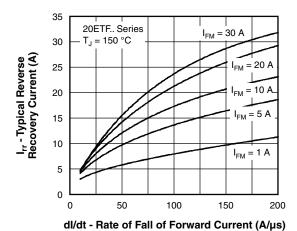


Fig. 13 - Recovery Current Characteristics,  $T_J = 150 \, ^{\circ}\text{C}$ 

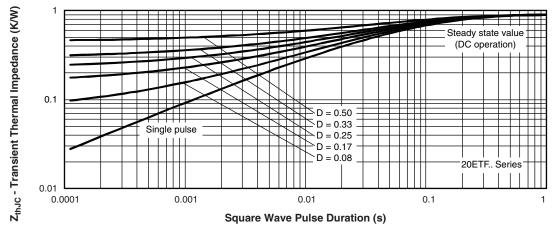


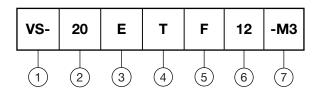
Fig. 14 - Thermal Impedance Z<sub>thJC</sub> Characteristics



# Vishay Semiconductors

### **ORDERING INFORMATION TABLE**

Device code



1 - Vishay Semiconductors product

- Current rating (20 = 20 A)

3 - Circuit configuration:

E = single

4 - Package:

T = TO-220AC 2L

5 - Type of silicon:

F = fast soft recovery rectifier

V 008 = 80

6 - Voltage ratings

10 = 1000 V 12 = 1200 V

7 - Environmental digit

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)								
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION						
VS-20ETF08-M3	50	Antistatic plastic tube						
VS-20ETF10-M3	50	Antistatic plastic tube						
VS-20ETF12-M3	50	Antistatic plastic tube						

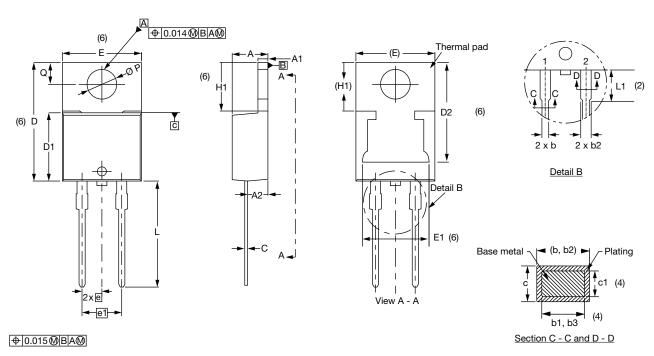
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?96156				
Part marking information	www.vishay.com/doc?95391				
SPICE model	www.vishay.com/doc?96866				

Revision: 29-Nov-2021 6 Document Number: 96214

# Vishay Semiconductors

## **TO-220AC 2L**

### **DIMENSIONS** in millimeters and inches



Lead tip

Conforms to JEDEC® outline TO-220AC

SYMBOL	MILLIMETERS		INC	INCHES		NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOIES	STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183			D2	11.68	13.30	0.460	0.524	6, 7
A1	1.14	1.40	0.045	0.055			Е	10.11	10.51	0.398	0.414	3, 6
A2	2.50	2.92	0.098	0.115			E1	6.86	8.89	0.270	0.350	6
b	0.69	1.01	0.027	0.040			е	2.41	2.67	0.095	0.105	
b1	0.38	0.97	0.015	0.038	4		e1	4.88	5.28	0.192	0.208	
b2	1.20	1.73	0.047	0.068			H1	6.09	6.48	0.240	0.255	6
b3	1.14	1.73	0.045	0.068	4		L	13.52	14.02	0.532	0.552	
С	0.36	0.61	0.014	0.024			L1	3.32	3.82	0.131	0.150	2
c1	0.36	0.56	0.014	0.022	4		ØΡ	3.54	3.91	0.139	0.154	
D	14.85	15.35	0.585	0.604	3		Q	2.60	3.00	0.102	0.118	
D1	8.38	9.02	0.330	0.355				•	•			

#### Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3, and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- $^{(7)}\,$  Outline conforms to JEDEC® TO-220, except D2

Revision: 07-Mar-2022 1 Document Number: 96156

# **Legal Disclaimer Notice**



Vishay

## **Disclaimer**

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

© 2022 VISHAY INTERTECHNOLOGY, INC. ALL RIGHTS RESERVED